



DMN22M5UFG

20V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
20V	$2.5 \text{m}\Omega @ \text{V}_{\text{GS}} = 4.5 \text{V}$	27A
	$3.5 \mathrm{m}\Omega @ \mathrm{V}_{\mathrm{GS}} = 2.5 \mathrm{V}$	23A

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

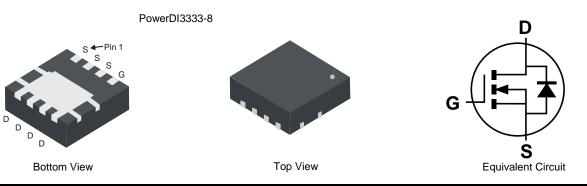
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} Ensures On State Losses are Minimized
- Small Form Factor, Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.
- https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN22M5UFG-7	PowerDI3333-8	2,000/Tape & Reel
DMN22M5UFG-13	PowerDI3333-8	3,000/Tape & Reel

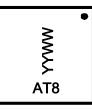
Notes:

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



AT8= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
	Steady	$T_{\rm C}$ = +25°C	ID	27	А
Continuous Drain Current (Note 7) $V_{GS} = 4.5V$	State	$T_C = +70^{\circ}C$		22	
Maximum Continuous Body Diode Forward Current (Note 6)			I _S	3	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I _{DM}	500	А
Pulsed Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)			I _{SM}	500	А
Avalanche Current , L = 0.2mH (Note 8)			I _{AS}	30	A
Repetitive Avalanche Energy, L = 0.2mH (Note 8)			E _{AS}	175	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	127	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	56	°C/W
Thermal Resistance, Junction to Case (Note 7)		R _{θJC}	1.7	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	20			V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}			1	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		—	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	0.5	_	1.3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	1.5	2.5	mΩ	$V_{GS} = 4.5V, I_D = 13.5A$	
	RDS(ON)	_	2.0	3.5	11122	V _{GS} = 2.5V, I _D = 13.5A	
Diode Forward Voltage	V _{SD}	_		1.2	V	$V_{GS} = 0V, I_S = 2A$	
DYNAMIC CHARACTERISTICS (Note 10)	-						
Input Capacitance	Ciss	_	3926	—	pF		
Output Capacitance	Coss	_	710	—	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	—	538	—	pF		
Gate Resistance	Rg	—	0.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	53	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg		99	—	nC		
Gate-Source Charge	Q _{gs}	-	3.7	_	nC	$V_{DS} = 16V, I_D = 27A$	
Gate-Drain Charge	Q _{gd}		24.4	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	8.1	_	ns		
Turn-On Rise Time	t _R		22.5	_	ns	$V_{GS} = 5V, V_{DS} = 10V,$ $R_g = 4.7\Omega, I_D = 13.5A$	
Turn-Off Delay Time	t _{D(OFF)}		72.1	_	ns		
Turn-Off Fall Time	t _F		44.5	_	ns		
Body Diode Reverse Recovery Time	t _{RR}	_	23.3	—	ns	I _F = 13.5A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	_	11.5	_	nC	I _F = 13.5A, di/dt = 100A/µs	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

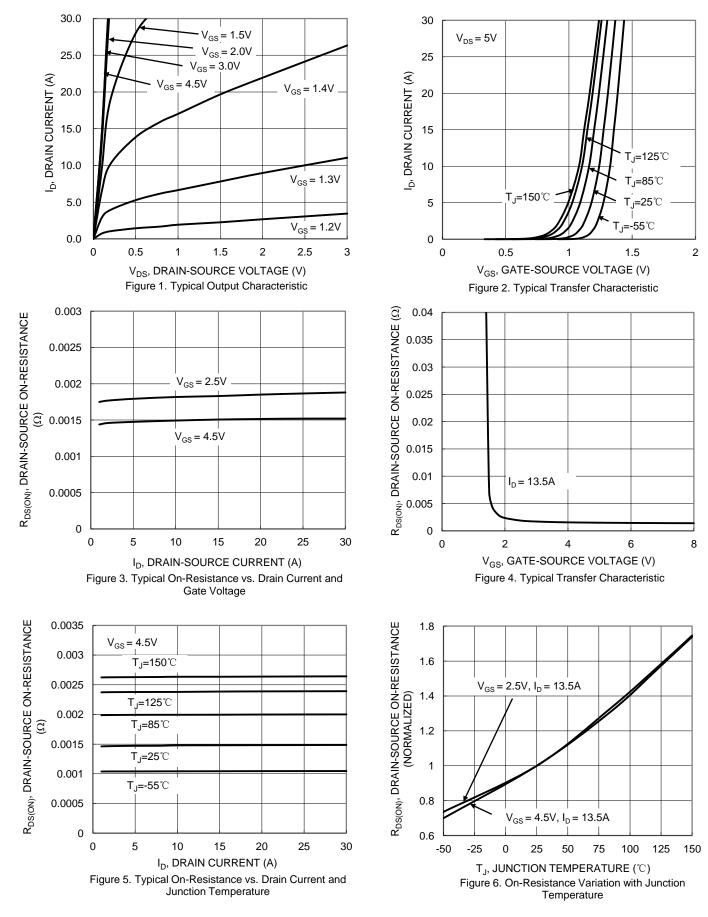
7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8. Ias and Eas ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



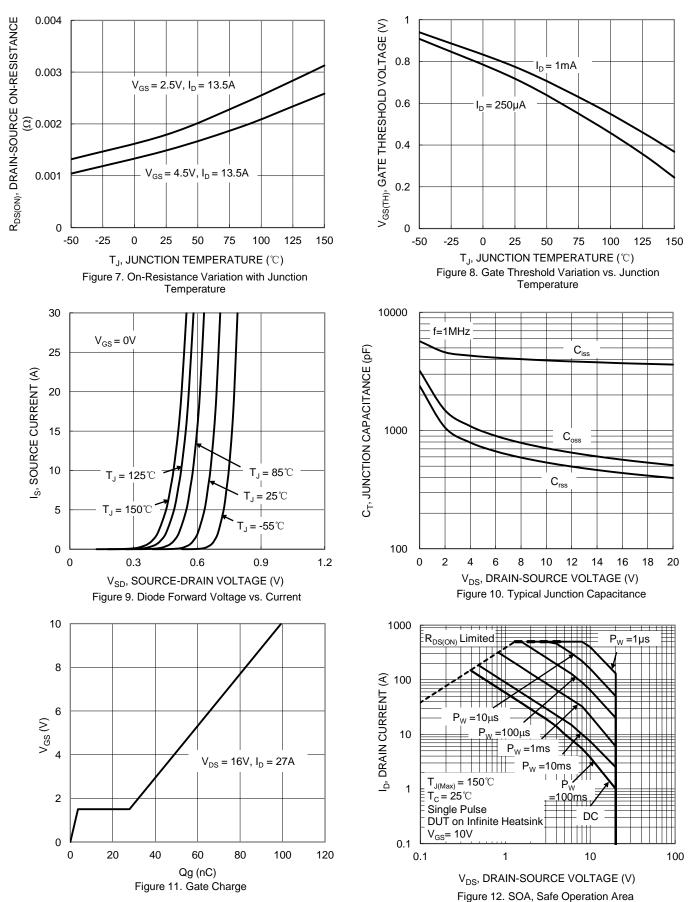
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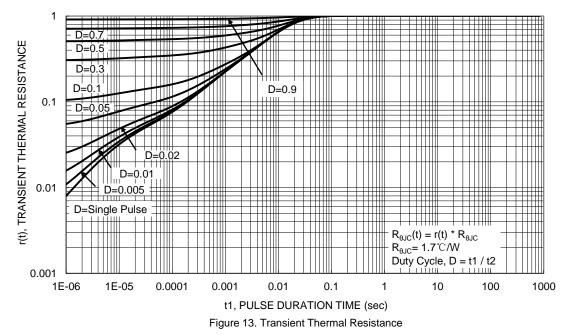
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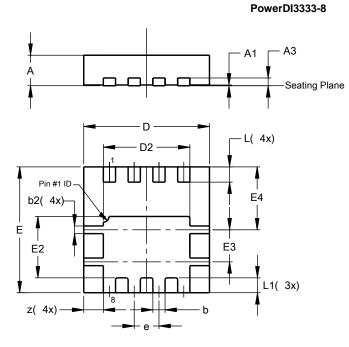






Package Outline Dimensions

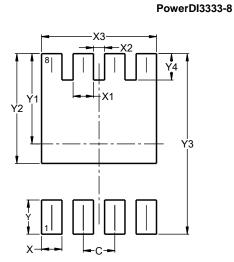
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
Z	_	-	0.515			
All I	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions Value (in mm) 0.650 0.420 С Х X1 0.420 Х2 0.230 Х3 2.370 Υ 0.700 1.850 Y1 Y2 2.250 Y3 3.700 Y4 0.540

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